

VertaCoat XP

Automated Silane Monolayer Vapor Deposition System



The YES VertaCoat XP system provides automated wafer handling and process solutions for silane monolayer deposition applications.

APPLICATIONS

- · Apply ultra-thin, conformal, monolayer coatings of chemical adhesion-promoters
- Precisely control surface hydrophobicity for MEMS device and micro LED anti-stiction solutions
- Provide highly uniform acrylate or epoxy-type adhesive coatings and interface layers for optical and AR/VR applications
- For nanoimprint lithography (NIL) applications, apply anti-adhesion coatings to prolong stamping tool lifetimes
- In Life Sciences, apply silane surface monolayers for stable, covalent linkage between solid substrates and biomolecules, including DNA and proteins
- Thin self-assembled monolayer (SAM) coating for selective deposition in semiconductor applications

KEY FEATURES

- Options for single process module two load port EFEM, or two process module four load port EFEM
- Large capacity chamber fits up to fifty 200/300 mm wafers
- Coating temperatures up to 250°C with ≤1.5% temp uniformity and multi-zone control
- Up to 5 vaporization lines with precision mass flow and thermal control
- Remote downstream plasma generator produces reactive atomic oxygen species for removal of organic residues from the chamber

BENEFITS

- Low pressure process reduces need for high operating temperatures that cause wafer warp and damage
- Superior chemical deposition uniformity; contact angle control within +/- 3 degrees
- Compatible with large selection of organosilanes including amino, epoxy, alkyl and chloro-silanes
- · Integrated plasma chamber cleaning process helps maintain run-to-run process uniformity
- · Eco-friendly, with significantly less chemical/solvent usage than wet chemical processes



VertaCoat XP SPECIFICATIONS

	SPECIFICATIONS
HARDWARE	
Integral EFEM	Class 1 (ISO 3) EFEM Module with 2 (two) Load ports Interchangeable capability for handling 200mm and 300mm wafers Capability to wafer map FOUPs & PM rack for cross slotting & double slot protection
Wafer Size	Configurable for 200 or 300 mm wafers, or available as bridge tool with dual handling capability
Capacity	200mm only configuration: 50 wafers 200mm/300mm option configuration: 25 wafers 300mm only configuration: 50 wafers
Vapor Delivery	Up to 5 vaporization lines with precision mass flow and thermal control
Chamber Material	316L stainless steel
Process Gas Inputs	2 standard (3 optional), pre-heated
Integrated Plasma	13.56 MHz
SOFTWARE	
Operating System	Windows-based recipe management, SECS/GEM compliant. Compliant with SEMI standards: E30, E39, E40, E87, E90, E94
PERFORMANCE	
Environmental Cleanliness	Class 1 (ISO 3)
Operating Temperature Range	50-250°C
Temperature Uniformity	± 1.5% after stabilization
Chamber Pressure Control	200 mT to 100 T
Chemical Usage	Typical process 1 - 10 mL
Up-time	>95%

BITA ELECTRONIQUE S.A.

618 BOITE POSTALE | LU-2016 LUXEMBOURG VILLE | www.bita.lu | info@bita.lu